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SMALL SIGNAL SCHOTTKY DIODE

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DESCRIPTION

Metal to silicon junction diode featuring high breakdown, low turn-on voltage and ultrafast switching. Primarly intended for high level UHF/VHF detection and pulse application with broad dynamic range. Matched batches are available on request.

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit	
V _{RRM}	Repetitive Peak Reverse Voltage	Repetitive Peak Reverse Voltage		V	
IF	Forward Continuous Current*	T _a = 25 °C	15	mA	
P _{tot}	Power Dissipation*	$T_a = 25^{\circ}C$	430	mW	
T _{stg} Tj	Storage and Junction Temperature Range		- 65 to 200 - 65 to 200	°C	
TL	Maximum Lead Temperature for Soldering during 10s at 4mm from Case		230	°C	

THERMAL RESISTANCE

Symbol	Test Conditions	Value	Unit
R _{th(j-a)}	Junction-ambient*	400	°C/W

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

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Symbol	WW.100	Test Conditions	Min.	Тур.	Max.	Unit
V_{BR}	$T_{amb} = 25^{\circ}C$	$I_R = 10\mu A$	70	N	WW	V V
V _F * *	$T_{amb} = 25^{\circ}C$	$I_F = 1 m A$	100 Y. COM. T	< 1	0.41	V
	$T_{amb} = 25^{\circ}C$	I _F = 15mA	.1001. OM.		1	WW.1001
l _R * *	$T_{amb} = 25^{\circ}C$	$V_R = 50V$	N 1007.	IN	0.2	μΑ

DYNAMIC CHARACTERISTICS

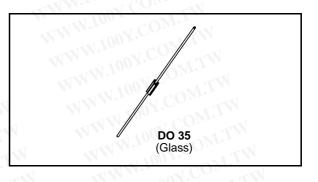
Symbol	WITT	Test Condition	ns	Min.	Тур.	Max.	Unit
С	$T_{amb} = 25^{\circ}C$	$V_R = 0V$	f = 1MHz	02.	M.L.	2	pF
τ	$T_{amb} = 25^{\circ}C$	$I_F = 5mA$	Krakauer Method	001.0	T.M	100	ps

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* On infinite heatsink with 4mm lead length ** Pulse test: $t_p \le 300 \mu s \ \delta < 2\%$. Matched batches available on request. Test conditions (forward voltage and/or capacitance) according to customer specification. WW.100Y.CO

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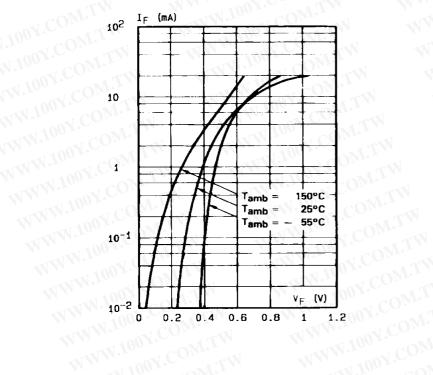


Figure 1. Forward current versus forward voltage at low level (typical values).

Figure 2. Capacitance C versus reverse applied voltage V_R (typical values).

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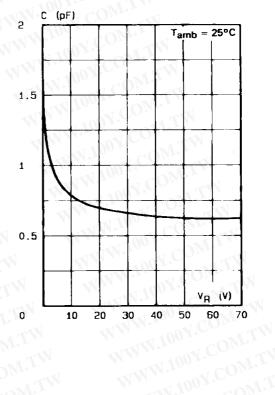
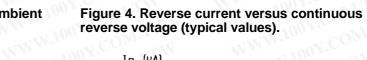
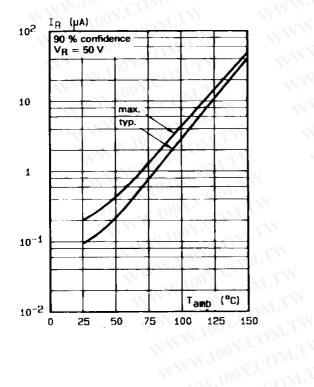


Figure 3. Reverse current versus ambient temperature.





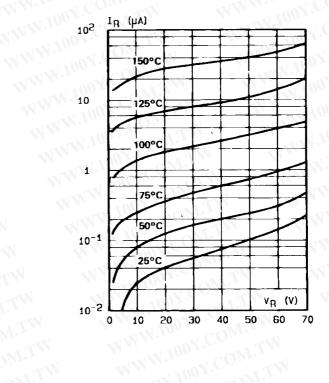
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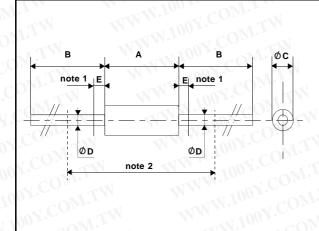
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PACKAGE MECHANICAL DATA





WW	DIMENSIONS					
REF.	Millin	Millimeters		hes		
N.	Min.	Max.	Min.	Max.		
A	3.05	4.50	0.120	0.177		
в	1.53	2.00	0.060	0.079		
С	12.7	100Y.CC	0.500			
D	0.458	0.558	0.018	0.022		
		-1				

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Cooling method : by convection and conduction Marking: clear, ring at cathode end. Weight: 0.15g WWW.100Y.COM

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